

CD4066BM/CD4066BC Quad Bilateral Switch

General Description

The CD4066BM/CD4066BC is a quad bilateral switch intended for the transmission or multiplexing of analog or digital signals. It is pin-for-pin compatible with CD4016BM/ CD4016BC, but has a much lower "ON" resistance, and "ON" resistance is relatively constant over the input-signal range.

Features

■ Wide supply voltage range 3V to 15V ■ High noise immunity 0.45 V_{DD} (typ.)

■ Wide range of digital and \pm 7.5 V_{PEAK} analog switching

■ "ON" resistance for 15V operation Ω 08

■ Matched "ON" resistance $\Delta R_{ON} = 5\Omega$ (typ.) over 15V signal input

■ "ON" resistance flat over peak-to-peak signal range

■ High "ON"/"OFF" 65 dB (typ.) output voltage ratio @ f_{is} = 10 kHz, R_L = 10 k Ω 0.1% distortion (typ.) ■ High degree linearity

@ $f_{is} = 1 \text{ kHz}, V_{is} = 5V_{p-p},$ High degree linearity High degree linearity $V_{DD}-V_{SS}=10V$, $R_L=10 \text{ k}\Omega$ ■ Extremely low "OFF" 0.1 nA (typ.) switch leakage @ $V_{DD} - V_{SS} = 10V$, $T_A = 25^{\circ}C$

■ Extremely high control input impedance $10^{12}\Omega(typ.)$

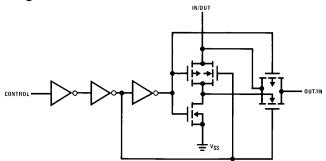
-50 dB (typ.) Low crosstalk between switches @ f_{is} =0.9 MHz, R_L =1 $k\Omega$

■ Frequency response, switch "ON" 40 MHz (typ.)

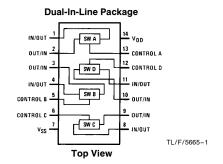
Applications

- Analog signal switching/multiplexing
 - · Signal gating
 - Squelch control
 - Chopper
 - Modulator/Demodulator
 - Commutating switch
- Digital signal switching/multiplexing
- CMOS logic implementation
- Analog-to-digital/digital-to-analog conversion
- Digital control of frequency, impedance, phase, and analog-signal-gain

Schematic and Connection Diagrams



Order Number CD4066B



Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{DD}) -0.5V to +18VInput Voltage (V_{IN}) -0.5V to V_{DD} + 0.5V -65°C to +150°C

Storage Temperature Range (T_S) Power Dissipation (PD)

700 mW

Lead Temperature (T_L) (Soldering, 10 seconds)

Dual-In-Line

Small Outline

500 mW 300°C

Recommended Operating

Conditions (Note 2)

Supply Voltage (V_{DD}) 3V to 15V Input Voltage (V_{IN}) 0V to $V_{\mbox{\scriptsize DD}}$

Operating Temperature Range (T_A) CD4066BM

 -55°C to $+125^{\circ}\text{C}$ CD4066BC -40°C to $+85^{\circ}\text{C}$

DC Electrical Characteristics CD4066BM (Note 2)

Symbol	Parameter	Conditions	−55°C			+ 25°C			+ 125°C	
Symbol			Min	Max	Min	Тур	Max	Min	Max	Units
I _{DD}	Quiescent Device Current	V _{DD} = 5V V _{DD} = 10V V _{DD} = 15V		0.25 0.5 1.0		0.01 0.01 0.01	0.25 0.5 1.0		7.5 15 30	μΑ μΑ μΑ
SIGNAL II	NPUTS AND OUTPUTS					•		•	•	•
R _{ON}	"ON" Resistance	$\begin{aligned} R_L &= 10 \text{ k}\Omega \text{ to } \frac{V_{DD} - V_{SS}}{2} \\ V_C &= V_{DD}, V_{IS} = V_{SS} \text{ to } V_{DD} \\ V_{DD} &= 5V \\ V_{DD} &= 10V \\ V_{DD} &= 15V \end{aligned}$		800 310 200		270 120 80	1050 400 240		1300 550 320	Ω Ω Ω
ΔR _{ON}	Δ"ON" Resistance Between any 2 of 4 Switches	$\begin{aligned} R_L &= 10 \text{ k}\Omega \text{ to} \frac{V_{DD} - V_{SS}}{2} \\ V_C &= V_{DD}, V_{IS} = V_{SS} \text{ to } V_{DD} \\ V_{DD} &= 10V \\ V_{DD} &= 15V \end{aligned}$				10 5				Ω
I _{IS}	Input or Output Leakage Switch "OFF"	$V_C=0$ $V_{IS}=15V$ and $0V$, $V_{OS}=0V$ and $15V$		±50		±0.1	±50		±500	nA
CONTRO	L INPUTS									
V _{ILC}	Low Level Input Voltage	$\begin{aligned} &V_{IS}\!=\!V_{SS} \text{ and } V_{DD} \\ &V_{OS}\!=\!V_{DD} \text{ and } V_{SS} \\ &I_{IS}\!=\!\pm10 \ \mu\text{A} \\ &V_{DD}\!=\!5V \\ &V_{DD}\!=\!10V \\ &V_{DD}\!=\!15V \end{aligned}$		1.5 3.0 4.0		2.25 4.5 6.75	1.5 3.0 4.0		1.5 3.0 4.0	V V V
V _{IHC}	High Level Input Voltage	V _{DD} = 5V V _{DD} = 10V (see note 6) V _{DD} = 15V	3.5 7.0 11.0		3.5 7.0 11.0	2.75 5.5 8.25		3.5 7.0 11.0		V V V
I _{IN}	Input Current	$V_{DD}-V_{SS}=15V$ $V_{DD}\geq V_{IS}\geq V_{SS}$ $V_{DD}\geq V_{C}\geq V_{SS}$		±0.1		±10 ⁻⁵	±0.1		± 1.0	μΑ

DC Electrical Characteristics CD4066BC (Note 2)

Symbol	Parameter	Conditions	-4	l0∘C	°C		+ 25°C		+ 85°C	
		Min	Max	Min	Тур	Max	Min	Max	Units	
I _{DD}	Quiescent Device Current	V _{DD} =5V		1.0		0.01	1.0		7.5	μΑ
		V _{DD} =10V		2.0		0.01	2.0		15	μΑ
-		V _{DD} = 15V		4.0		0.01	4.0		30	μΑ

Symbol	Parameter	Conditions	-40°C		+ 25°C			+ 85°C		Units
Symbol	raiametei	Conditions	Min	Max	Min	Тур	Max	Min	Max	Onits
SIGNAL II	NPUTS AND OUTPUTS									
R _{ON}	"ON" Resistance	$R_L = 10 \text{ k}\Omega \text{ to } \frac{V_{DD} - V_{SS}}{2}$ $V_C = V_{DD}, V_{SS} \text{ to } V_{DD}$ $V_{DD} = 5V$		850		270	1050		1200	Ω
		V _{DD} = 10V V _{DD} = 15V		330 210		120 80	400 240		520 300	Ω
ΔR _{ON}	Δ"ON" Resistance Between Any 2 of 4 Switches	$\begin{aligned} R_L &= 10 \text{ k}\Omega \text{ to } \frac{V_{DD} - V_{SS}}{2} \\ V_{CC} &= V_{DD}, V_{IS} = V_{SS} \text{ to } V_{DD} \\ V_{DD} &= 10V \\ V_{DD} &= 15V \end{aligned}$				10 5				Ω
I _{IS}	Input or Output Leakage Switch "OFF"	V _C =0		±50		±0.1	±50		±200	nA
CONTRO	INPUTS				•		•			
V _{ILC}	Low Level Input Voltage	$\begin{aligned} & V_{IS}\!=\!V_{SS} \text{ and } V_{DD} \\ & V_{OS}\!=\!V_{DD} \text{ and } V_{SS} \\ & I_{IS}\!=\!\pm10\mu\text{A} \\ & V_{DD}\!=\!5\text{V} \\ & V_{DD}\!=\!10\text{V} \\ & V_{DD}\!=\!15\text{V} \end{aligned}$		1.5 3.0 4.0		2.25 4.5 6.75	1.5 3.0 4.0		1.5 3.0 4.0	V V
V _{IHC}	High Level Input Voltage	V _{DD} = 5V V _{DD} = 10V (See note 6) V _{DD} = 15V	3.5 7.0 11.0		3.5 7.0 11.0	2.75 5.5 8.25		3.5 7.0 11.0		V V V
I _{IN}	Input Current	$V_{DD}-V_{SS}=15V$ $V_{DD}\geq V_{IS}\geq V_{SS}$ $V_{DD}\geq V_{C}\geq V_{SS}$		±0.3		±10 ⁻⁵	±0.3		±1.0	μΑ

AC Electrical Characteristics * $\rm T_A = 25^{\circ}C,\, t_r = t_f = 20~ns$ and $\rm V_{SS} = 0V$ unless otherwise noted

Symbol	Parameter	Conditions	Min	Тур	Max	Units
t _{PHL} , t _{PLH}	Propagation Delay Time Signal Input to Signal Output	V _C =V _{DD} , C _L =50 pF, (<i>Figure 1</i>) R _L =200k				
		V _{DD} =5V		25	55	ns
		V _{DD} =10V		15	35	ns
		V _{DD} =15V		10	25	ns
t _{PZH} , t _{PZL}	Propagation Delay Time	$R_L = 1.0 \text{ k}\Omega$, $C_L = 50 \text{ pF}$, (Figures 2 and 3)				
	Control Input to Signal	V _{DD} =5V			125	ns
	Output High Impedance to	V _{DD} =10V			60	ns
	Logical Level	V _{DD} =15V			50	ns
t _{PHZ} , t _{PLZ}	Propagation Delay Time	$R_L = 1.0 \text{ k}\Omega$, $C_L = 50 \text{ pF}$, (Figures 2 and 3)				
	Control Input to Signal	V _{DD} =5V			125	ns
	Output Logical Level to	V _{DD} =10V			60	ns
	High Impedance	V _{DD} =15V			50	ns
	Sine Wave Distortion	$V_{C} = V_{DD} = 5V, V_{SS} = -5V$		0.1		%
		$R_L = 10 \text{ k}\Omega, V_{IS} = 5V_{p-p}, f = 1 \text{ kHz},$				
		(Figure 4)				
	Frequency Response-Switch	$V_C = V_{DD} = 5V, V_{SS} = -5V,$		40		MHz
	"ON" (Frequency at -3 dB)	$R_L = 1 \text{ k}\Omega, V_{IS} = 5V_{p-p},$				
		20 Log ₁₀ V _{OS} /V _{OS} (1 kHz) – dB,				
		(Figure 4)				

ntinued) $T_A = 25^{\circ}\text{C}$, $t_r = t_f = 20 \text{ ns}$ and $V_{SS} = 0\text{V}$ unless otherwise noted
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Symbol	Parameter	Conditions	Min	Тур	Max	Units
	Feedthrough — Switch "OFF" (Frequency at -50 dB)	$V_{DD} = 5.0V$, $V_{CC} = V_{SS} = -5.0V$, $R_L = 1 \text{ k}\Omega$, $V_{IS} = 5.0V_{p-p}$, 20 Log ₁₀ , $V_{OS}/V_{IS} = -50 \text{ dB}$, (Figure 4)		1.25		
	Crosstalk Between Any Two Switches (Frequency at -50 dB)	$V_{DD} = V_{C(A)} = 5.0V; V_{SS} = V_{C(B)} = 5.0V,$ $R_{L}1 \text{ k}\Omega, V_{IS(A)} = 5.0 \text{ V}_{p-p}, 20 \text{ Log}_{10},$ $V_{OS(B)}/V_{IS(A)} = -50 \text{ dB}$ (Figure 5)		0.9		MHz
	Crosstalk; Control Input to Signal Output	$V_{DD} = 10V$, $R_L = 10 \text{ k}\Omega$, $R_{IN} = 1.0 \text{ k}\Omega$, $V_{CC} = 10V$ Square Wave, $C_L = 50 \text{ pF}$ (Figure 6)		150		mV _{p-p}
	Maximum Control Input	$R_L = 1.0 \text{ k}\Omega$, $C_L = 50 \text{ pF}$, (Figure 7) $V_{OS(f)} = \frac{1}{2} V_{OS}(1.0 \text{ kHz})$				
		V _{DD} = 5.0V V _{DD} = 10V V _{DD} = 15V		6.0 8.0 8.5		MHz MHz MHz
C _{IS}	Signal Input Capacitance			8.0		pF
C _{OS}	Signal Output Capacitance	V _{DD} =10V		8.0		pF
C _{IOS}	Feedthrough Capacitance	V _C =0V		0.5		pF
C _{IN}	Control Input Capacitance			5.0	7.5	pF

^{*}AC Parameters are guaranteed by DC correlated testing.

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.

Note 2: V_{SS}=0V unless otherwise specified.

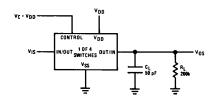
Note 3: These devices should not be connected to circuits with the power "ON".

Note 4: In all cases, there is approximately 5 pF of probe and jig capacitance in the output; however, this capacitance is included in C_L wherever it is specified.

 $\textbf{Note 5: } V_{IS} \text{ is the voltage at the in/out pin and } V_{OS} \text{ is the voltage at the out/in pin. } V_{C} \text{ is the voltage at the control input.}$

 $\textbf{Note 6:} \ \, \text{Conditions for V}_{IHC} : a) \ \, \text{V}_{IS} = \text{V}_{DD}, \ \, \text{I}_{OS} = \text{standard B series I}_{OH} \qquad \text{b) V}_{IS} = \text{0V}, \ \, \text{I}_{OL} = \text{standard B series I}_{OL}.$

AC Test Circuits and Switching Time Waveforms



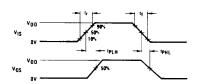
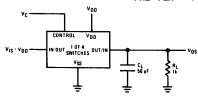
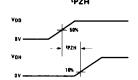


FIGURE 1. t_{PHL}, t_{PLH} Propagation Delay Time Signal Input to Signal Output





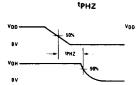
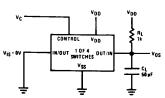
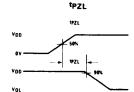


FIGURE 2. $t_{\mbox{\scriptsize PZH}}, t_{\mbox{\scriptsize PHZ}}$ Propagation Delay Time Control to Signal Output





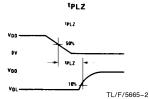
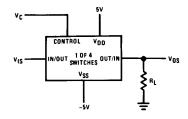
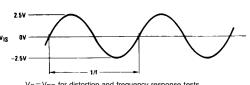


FIGURE 3. t_{PZL}, t_{PLZ} Propagtion Delay Time Control to Signal Output

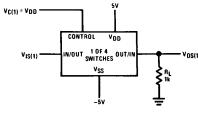
AC Test Circuits and Switching Time Waveforms (Continued)

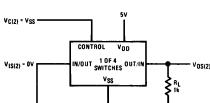




 $V_C\!=\!V_{DD}$ for distortion and frequency response tests $V_C\!=\!V_{SS}$ for feedthrough test

FIGURE 4. Sine Wave Distortion, Frequency Response and Feedthrough





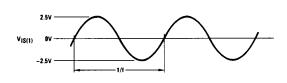
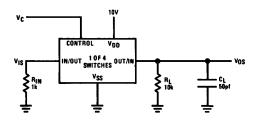


FIGURE 5. Crosstalk Between Any Two Switches



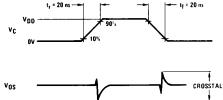
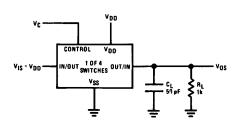


FIGURE 6. Crosstalk: Control Input to Signal Output



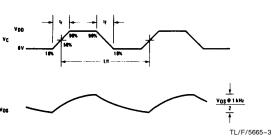
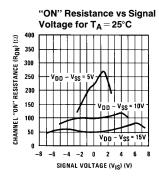
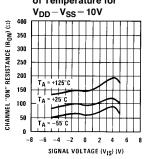


FIGURE 7. Maximum Control Input Frequency

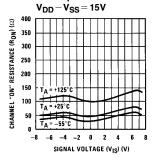
Typical Performance Characteristics



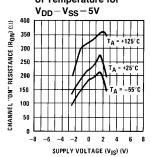
"ON" Resistance as a Function of Temperature for



"ON" Resistance as a Function of Temperature for



"ON" Resistance as a Function of Temperature for



TL/F/5665-4

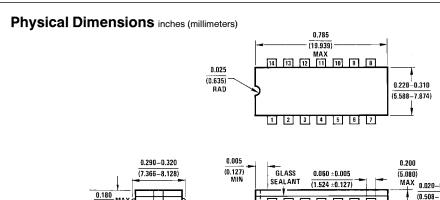
Special Considerations

In applications where separate power sources are used to drive V_{DD} and the signal input, the V_{DD} current capability should exceed V_{DD}/R_L ($R_L=$ effective external load of the 4 CD4066BM/CD4066BC bilateral switches). This provision avoids any permanent current flow or clamp action of the V_{DD} supply when power is applied or removed from CD4066BM/CD4066BC.

In certain applications, the external load-resistor current may include both $V_{\mbox{\scriptsize DD}}$ and signal-line components. To avoid

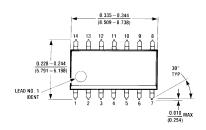
drawing V_{DD} current when switch current flows into terminals 1, 4, 8 or 11, the voltage drop across the bidirectional switch must not exceed 0.6V at $T_A\!\leq\!25^{\circ}\text{C}$, or 0.4V at $T_A\!>\!25^{\circ}\text{C}$ (calculated from R_{ON} values shown).

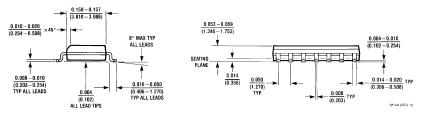
No V_{DD} current will flow through R_{L} if the switch current flows into terminals 2, 3, 9 or 10.



(5.080) MAX 0.020-0.060 0.180 (4.572) MAX (0.508-1.524) 95° ±5 _10° MAX 0.008-0.012 0.310-0.410 (0.203-0.305) D.018 ±0.003 0.125-0.200 0.098 (7.874-10.41) (0.457 ±0.076) (3.175-5.080) (2.489) MAX BOTH ENDS 0.100 ±0.010 0.150 (2.540 ±0.254) (3.81) J14A (REV G)

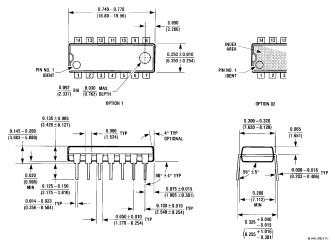
Cerdip (J) Order Number CD4066BMJ or CD4066BCJ NS Package Number J14A





S.O. Package (M) Order Number CD4066BCM NS Package Number M14A

Physical Dimensions inches (millimeters) (Continued)



Dual-In-Line Package (N)
Order Number CD4066BMN or CD4066BCN
NS Package Number N14A

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- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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